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Kind regards,

Team Nexperia

PDTA114T series

PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = open Rev. 07 — 20 April 2007 Product data s

Product data sheet

Product profile

1.1 General description

PNP Resistor-Equipped Transistors (RET) family in small plastic packages.

Table 1. **Product overview**

Type number	Package	NPN complement		
	NXP	JEITA	JEDEC	
PDTA114TE	SOT416	SC-75	-	PDTC114TE
PDTA114TK	SOT346	SC-59A	TO-236	PDTC114TK
PDTA114TM	SOT883	SC-101	-	PDTC114TM
PDTA114TS[1]	SOT54	SC-43A	TO-92	PDTC114TS
PDTA114TT	SOT23	-	TO-236AB	PDTC114TT
PDTA114TU	SOT323	SC-70	-	PDTC114TU

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2).

1.2 Features

- 100 mA output current capability
- Built-in bias resistors
- Simplifies circuit design
- Reduces component count
- Reduces pick and place costs

1.3 Applications

- Digital applications
- Control of IC inputs

- Cost-saving alternative to BC857 series in digital applications
- Low current peripheral driver

1.4 Quick reference data

Table 2. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CEO}	collector-emitter voltage	open base	-	-	-50	V
Io	output current		-	-	-100	mA
R1	bias resistor 1 (input)		7	10	13	kΩ



2. Pinning information

Table 3. **Pinning** Pin Description Simplified outline **Symbol** SOT54 1 input (base) output (collector) 3 GND (emitter) 006aaa217 SOT54A input (base) 2 output (collector) 3 GND (emitter) R1 001aab348 006aaa217 **SOT54** variant input (base) 2 output (collector) 3 GND (emitter) (B -001aab447 006aaa217 SOT23; SOT323; SOT346; SOT416 input (base) 3 2 GND (emitter) 3 output (collector) 2 006aaa144 sym009 **SOT883** 1 input (base) 2 GND (emitter) 3 output (collector) Transparent top view

3. Ordering information

Table 4. Ordering information

Type number	Package						
	Name	Description	Version				
PDTA114TE	SC-75	plastic surface-mounted package; 3 leads	SOT416				
PDTA114TK	SC-59A	plastic surface-mounted package; 3 leads	SOT346				
PDTA114TM	SC-101	leadless ultra small plastic package; 3 solder lands; body 1.0 \times 0.6 \times 0.5 mm	SOT883				
PDTA114TS[1]	SC-43A	plastic single-ended leaded (through hole) package; 3 leads	SOT54				
PDTA114TT	-	plastic surface-mounted package; 3 leads	SOT23				
PDTA114TU	SC-70	plastic surface-mounted package; 3 leads	SOT323				

^[1] Also available in SOT54A and SOT54 variant packages (see Section 2 and Section 9).

4. Marking

Table 5. Marking codes

rabio or marking could	
Type number	Marking code ^[1]
PDTA114TE	11
PDTA114TK	23
PDTA114TM	DE
PDTA114TS	TA114T
PDTA114TT	*11
PDTA114TU	*23

^{[1] * = -:} made in Hong Kong

^{* =} p: made in Hong Kong

^{* =} t: made in Malaysia

^{* =} W: made in China

5. Limiting values

Table 6. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter	-	-50	V
V_{CEO}	collector-emitter voltage	open base	-	-50	V
V_{EBO}	emitter-base voltage	open collector	-	-5	V
lo	output current		-	-100	mA
I _{CM}	peak collector current	single pulse; $t_p \le 1 \text{ ms}$	-	-100	mA
P _{tot}	total power dissipation	$T_{amb} \le 25 ^{\circ}C$			
	PDTA114TE		<u>[1]</u> _	150	mW
	PDTA114TK		<u>[1]</u> _	250	mW
	PDTA114TM		[2][3]	250	mW
	PDTA114TS		<u>[1]</u> _	500	mW
	PDTA114TT		<u>[1]</u> -	250	mW
	PDTA114TU		<u>[1]</u> _	200	mW
Tj	junction temperature		-	150	°C
T _{amb}	ambient temperature		-65	+150	°C
T _{stg}	storage temperature		-65	+150	°C

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated and standard footprint.

6. Thermal characteristics

Table 7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from junction to ambient	in free air				
	PDTA114TE	<u>]</u>	1] _	-	833	K/W
	PDTA114TK	<u>]</u>	1] _	-	500	K/W
	PDTA114TM	[2][3] _	-	500	K/W
	PDTA114TS	<u>[</u>	1] _	-	250	K/W
	PDTA114TT	<u>[</u>	<u>1]</u> _	-	500	K/W
	PDTA114TU	<u>]</u>	1] _	-	625	K/W

^[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

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^[2] Reflow soldering is the only recommended soldering method.

^[3] Device mounted on an FR4 PCB with 60 µm copper strip line, standard footprint.

^[2] Reflow soldering is the only recommended soldering method.

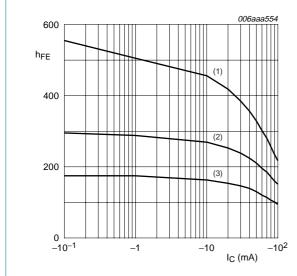
^[3] Device mounted on an FR4 PCB with 60 μm copper strip line, standard footprint.

Characteristics 7.

Table 8. **Characteristics**

T_{amb} = 25 °C unless otherwise specified.

· allib =0						
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off current	$V_{CB} = -50 \text{ V}; I_E = 0 \text{ A}$	-	-	-100	nA
I_{CEO}	collector-emitter	$V_{CE} = -30 \text{ V}; I_{B} = 0 \text{ A}$	-	-	-1	μΑ
	cut-off current	$V_{CE} = -30 \text{ V}; I_{B} = 0 \text{ A};$ $T_{j} = 150 ^{\circ}\text{C}$	-	-	-50	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_C = 0 \text{ A}$	-	-	-100	nA
h _{FE}	DC current gain	$V_{CE} = -5 \text{ V}; I_{C} = -1 \text{ mA}$	200	-	-	
V _{CEsat}	collector-emitter saturation voltage	$I_C = -10 \text{ mA};$ $I_B = -0.5 \text{ mA}$	-	-	-150	mV
R1	bias resistor 1 (input)		7	10	13	$k\Omega$
C _c	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = i_e = 0 \text{ A};$ f = 1 MHz	-	-	3	pF



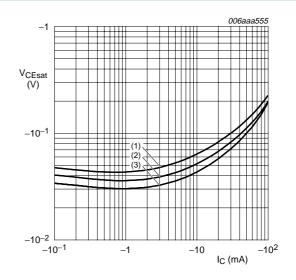


- (1) $T_{amb} = 150 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$

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(3) $T_{amb} = -40 \, ^{\circ}C$

Fig 1. DC current gain as a function of collector current; typical values



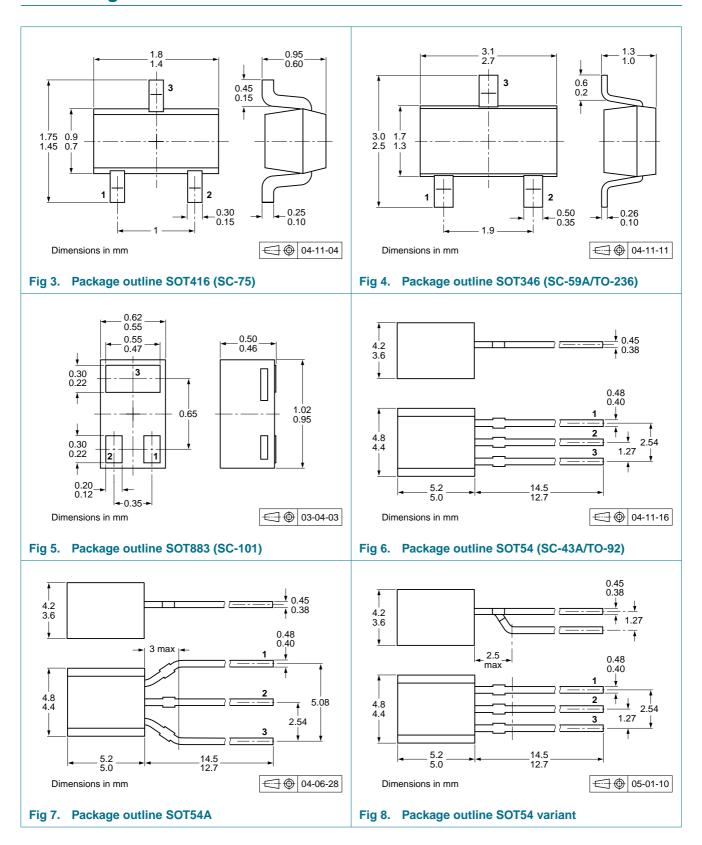
$$I_C/I_B = 20$$

- (1) $T_{amb} = 100 \, ^{\circ}C$
- (2) $T_{amb} = 25 \, ^{\circ}C$
- (3) $T_{amb} = -40 \, ^{\circ}C$

Fig 2. Collector-emitter saturation voltage as a function of collector current; typical values

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8. Package outline



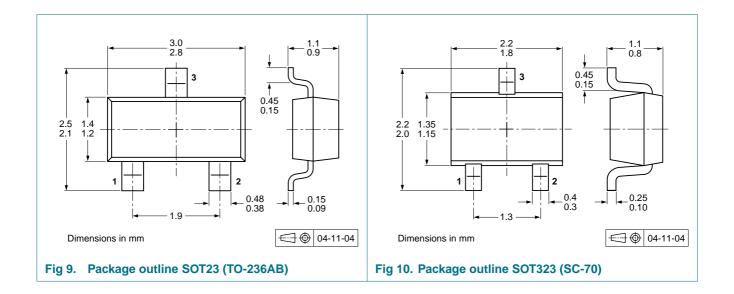
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PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = open



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Product data sheet

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PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = open

Packing information

Table 9. **Packing methods**

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

		3				
Type number	Package	Description	Packin	Packing quantity		
			3000	5000	10000	
PDTA114TE	SOT416	4 mm pitch, 8 mm tape and reel	-115	-	-135	
PDTA114TK	SOT346	4 mm pitch, 8 mm tape and reel	-115	-	-135	
PDTA114TM	SOT883	2 mm pitch, 8 mm tape and reel	-	-	-315	
PDTA114TS	SOT54	bulk, straight leads	-	-412	-	
	SOT54A	tape and reel, wide pitch	-	-	-116	
		tape ammopack, wide pitch	-	-	-126	
	SOT54 variant	bulk, delta pinning	-	-112	-	
PDTA114TT	SOT23	4 mm pitch, 8 mm tape and reel	-215	-	-235	
PDTA114TU	SOT323	4 mm pitch, 8 mm tape and reel	-115	-	-135	

^[1] For further information and the availability of packing methods, see Section 12.

10. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes			
PDTA114T_SER_7	20070420	Product data sheet	-	PDTA114T_SERIES_6			
Modifications:		of this data sheet has been of NXP Semiconductors.	redesigned to comply v	with the new identity			
	Legal texts have been adapted to the new company name where appropriate.						
	Type number PDTA114TEF removed						
	Section 1.2	"Features": amended					
	• Section 1.3	"Applications": amended					
	Table 4 "Ordering information": added						
	 Table 5 "Ma 	rking codes": enhanced tab	le note section				
	• Table 6 "Lim	niting values": I _{CM} peak colle	ector current conditions	added			
	• Figure 1, 2,	7 and 8: added					
	• Figure 3, 4,	5, 6, 9 and 10: superseded	by minimized package	outline drawings			
	 Section 9 "F 	Packing information": added					
	Section 11 '	"Legal information": updated	I				
PDTA114T_SERIES_6	20040802	Product specification	-	PDTA114T_SERIES_5			
PDTA114T_SERIES_5	20030909	Product specification	-	PDTA114T_SERIES_4			
PDTA114T_SERIES_4	20030410	Product specification	-	PDTA114TE_2			
				PDTA114TK_3			
				PDTA114TS_2 PDTA114TT 3			
				PDTA114TU_3			
PDTA114TE_2	19980723	Preliminary specification	-	PDTA114TE_1			
PDTA114TK_3	19980515	Product specification	-	PDTA114TK_2			
PDTA114TS_2	19980515	Product specification	-	PDTA114TS_1			
		Objective specification	-	DDTA444TT 0			
PDTA114TT_3	19990413	Objective specification	-	PDTA114TT_2			

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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PDTA114T series

PNP resistor-equipped transistors; R1 = 10 k Ω , R2 = open

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Date of release: 20 April 2007 Document identifier: PDTA114T_SER_7



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